

C 32343

(Pages : 2)

Name.....

Reg. No.....

FIRST SEMESTER M.Sc. DEGREE EXAMINATION, DECEMBER 2017

(CUCSS)

Physics

PHY 1C 04—ELECTRONICS

(2012 Admissions)

Time : Three Hours

Maximum : 36 Weightage

Section A

Answer all questions.

Each question carries a weightage of 1.

1. What is drain resistance ? Give the relation between drain resistance and drain current.
2. Draw the volt-ampere drain characteristics of a P-channel E-MOSFET.
3. What is the basic principle of the working of LDR ? Mention its application:-
4. Write the relation between light intensity in a semiconductor and absorption coefficient. What is its significance ?
5. What are the characteristics of an ideal op amp ?
6. What is the slew rate of an op amp ? Write the relation between maximum frequency of the signal voltage and slew rate.
7. Why Schmitt trigger is preferred to zero crossing detector ?
8. Explain the functions of ALE and $\overline{IO/\overline{m}}$ signals of the 8085 microprocessor.
9. Write the description of the following instructions : INR C, JM 3000H, JMP 2085H, OUT 01H.
10. Compare C MOS with TTL.
11. The FF is essentially a 1-bit memory. Why ?
12. In analogue computers, integrators are preferred to differentiators. Why ?

(12 × 1 = 12 weightage)

Turn over

Section B

Answer any two questions.

Each question carries a weightage of 6.

13. Explain the working of MOSFET under depletion mode. Also explain the working of enhancement type MOSFET
14. What is a tunnel diode? Explain the principle of working of a tunnel diode, giving its characteristics.
15. Explain how a square wave is generated in an op amp based square wave generator.
16. What is a ripple counter? Why is it called so? How many FF s would be needed to count the number 7? Explain its working.

(2 × 6 = 12 weightage)

Section C

Answer any four questions.

Each carries a weightage of 3.

17. When V_{GS} of a FET changes from -3.1 V to 3 V, the drain current changes from 1 mA to 1.3 mA? Find the value of transconductance.
18. A photodiode has a quantum efficiency of 65% when photons of energy 1.5×10^{-19} J are incident upon it. At what wavelength is the photodiode operating?
19. What is the error in the differential output, if the inputs $V_1 = 1050 \mu\text{V}$, $V_2 = 950 \mu\text{V}$ and $\text{CMRR} = 1000$?
20. Design a high pass filter for a cut-off frequency of 2 kHz and pass band gain 2 .
21. The inverting and non-inverting terminals of an opamp are grounded. If the op amp has an input offset voltage of 5 mV and an open loop voltage gain of $10,000$, then what will be the output voltage?
22. Write an assembly language programme for adding the contents of the memory location 8000H and 8050H . Store the result in 8100H .

(4 × 3 = 12 weightage)